

Description

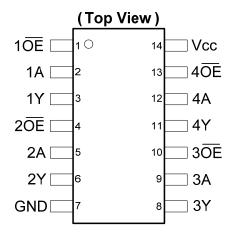
The 74AHC125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that when driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 2.0V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment.

Features

Notes:

- Wide Supply Voltage Range from 2.0V to 5.5V
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs can be driven by 3.3 V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- · Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

 $1.\ No\ purposely\ added\ lead.\ Fully\ EU\ Directive\ 2002/95/EC\ (RoHS)\ \&\ 2011/65/EU\ (RoHS\ 2)\ compliant.$

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



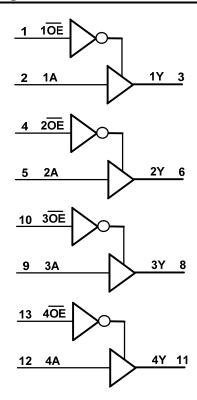
Pin Descriptions

Pin Number	Pin Name	Function		
1	10E	Data Enable Input (active low)		
2	1A	Data Input		
3	1Y	Data Output		
4	2 OE	Data Enable Input (active low)		
5	2A	Data Input		
6	2Y	Data Output		
7	GND	Ground		
8	3Y	Data Output		
9	3A	Data Input		
10	3OE	Data Enable Input (active low)		
11	4Y	Data Output		
12	4A	Data Input		
13	4 0E	Data Enable Input (active low)		
14	V _{CC}	Supply Voltage		

Function Table

Inp	Output	
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	X	Z

Logic Diagram



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
lok	Output Clamp Current V _O < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} + 0.5V	25	mA
lo	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
Icc	Continuous Current Through V _{CC}	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Λ+/Λ\ <i>/</i>	Input Transition Dies or Fall Date	V _{CC} = 3.0V to 3.6V		100	no/\/
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 4.5V to 5.5V		20	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Comple ed	Davamatan	Took Conditions	v	T _A = -40°	T _A = -40°C to +85°C		T _A = -40°C to +125°C		
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit	
			2.0V	1.5		1.5			
V_{IH}	High-Level Input Voltage		3.0V	2.1		2.1		V	
			5.5V	3.85		3.85			
			2.0V		0.5		0.5		
V_{IL}	Low-Level Input Voltage		3.0V		0.9		0.9	V	
			5.5V		1.65		1.65		
		I _{OH} = -50μA	2.0V	1.9		1.9			
		I _{OH} = -50μA	3.0V	2.9		2.9		V	
V_{OH}	High-Level Output Voltage	I _{OH} = -50μA	4.5V	4.4		4.4			
		I _{OH} = -4mA	3.0V	2.48		2.40			
		I _{OH} = -8mA	4.5V	3.80		3.70		1	
		I _{OL} = 50μA	2.0V		0.1		0.1		
		I _{OL} = 50μA	3.0V		0.1		0.1	1	
V_{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V		0.1		0.1	V	
		I _{OL} = 4mA	3.0V		0.44		0.55	1	
		I _{OL} = 8mA	4.5V		0.44		0.55	1	
l _{OZ}	Z State Leakage Current	V _O = 0 to 5.5V V _I = GND or 5.5V	5.5V		±2.5		±10	μА	
lı	Input Current	V _I = GND to 5.5V	3.6V		±1		±2	μΑ	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μA	



Operating Characteristics

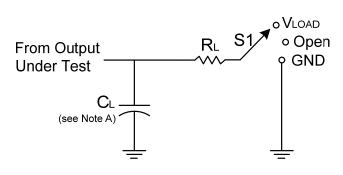
	Parameter	Test Conditions	V _{CC} = 2.0V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
$C_{\sf pd}$	Power Dissipation Capacitance per Gate	f = 1MHz	10.1	13.1	15	pF
Ci	Input Capacitance	$V_i = V_{CC} - \text{or GND}$	4.0	4.0	4.0	pF

Switching Characteristics

Cumbal	Dovemeter	Test	v		T _A = +25°(C	-40°C to	+85°C	-40°C t	o +125°C	Unit
Symbol	mbol Parameter Conditions		Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
		Figure 1	3.0V to 3.6V	0.5	4.4	8.0	0.5	9.5	0.5	11.5	
	Propagation	$C_L = 15pF$	4.5V to 5.5V	0.5	3.0	5.5	0.5	6.5	0.5	7.0	
t _{PD}	Delay A _N to Y _N	Figure 1	3.0V to 3.6V	0.5	6.2	11.5	0.5	13.0	0.5	14.5	ns
		C _L = 50pF	4.5V to 5.5 V	0.5	4.3	7.5	0.5	8.5	0.5	9.5	
		Figure 1	3.0V to 3.6V	0.5	4.7	8.0	0.5	9.5	0.5	11.5	
	Enable Time	$C_L = 15pF$	4.5V to 5.5V	0.5	3.3	5.1	0.5	6.0	0.5	7.5	
t _{EN}	TEN OEN to YN	Figure 1	3.0V to 3.6V	0.5	6.8	11.5	0.5	13.0	0.5	14.5	ns
		$C_L = 50pF$	4.5V to 5.5V	0.5	4.7	7.1	0.5	8.0	0.5	9.0	
		Figure 1	3.0V to 3.6V	0.5	6.7	9.7	0.5	11.5	0.5	12.5	
	$\begin{array}{c c} t_{DIS} & \begin{array}{c} Disable \ Time \\ \hline OE_N \ to \ Y_N \end{array} & \begin{array}{c} C_L = 15pF \\ \hline Figure \ 1 \\ C_L = 50pF \end{array} \end{array}$	Disable Time C _L = 15pF	4.5V to 5.5V	0.5	4.8	6.8	0.5	8.0	0.5	8.5	
τDIS		Figure 1	3.0 V to 3.6V	0.5	9.6	13.2	0.5	15.0	0.5	16.5	ns
		C _L = 50pF	$C_L = 50pF$	4.5V to 5.5V	0.5	6.8	8.8	0.5	10.0	0.5	11.0

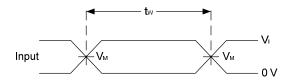


Parameter Measurement Information

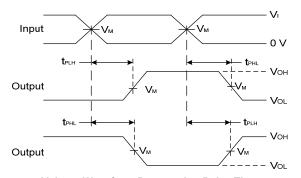


TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vload
t _{PHZ} /t _{PZH}	GND
	•

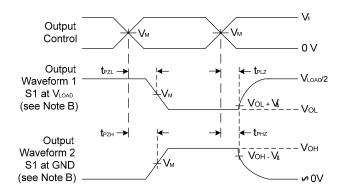
V	Inp	uts	V	V		Б	V/A
Vcc	VI	t _r /t _f	V _M	V _{LOAD}	CL	R_L	V Δ
3.3V±0.3V	3 V	≤3ns	V _{CC} /2	V _{CC}	15,50 pF	1ΚΩ	0.3 V
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	V _{CC}	15,50 pF	1ΚΩ	0.3 V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

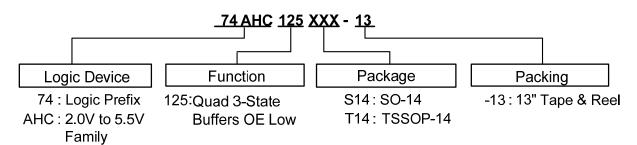
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLZ} and t_{PHZ} are the same as $t_{\text{dis.}}$
- E. t_{PZL} and t_{PZH} are the same as t_{EN0}
- F. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



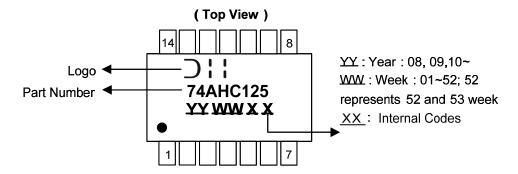
Ordering Information



	Device	Package Code Packaging		7" Tape	and Reel
	Device	Fackage Code	rackaging	Quantity	Part Number Suffix
Green	74AHC125S14-13	S14	SO-14	2500/Tape & Reel	-13
Green	74AHC125T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14



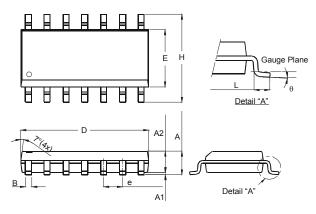
Part Number	Package
74AHC125S14	SO-14
74AHC125T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

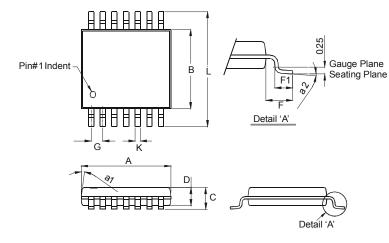
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Dimensions in mm						

Package Type: TSSOP-14



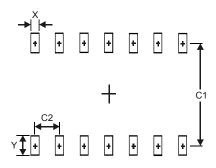
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
O		1.2
D	8.0	1.05
F	1.00 Typ	
F1	0.45	0.75
O	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



Suggested Pad Layout

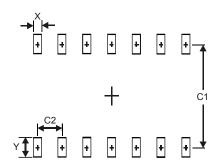
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65



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